

532nm Passive Q-Switched Laser



DESCRIPTION

For the passive Q-switched microchip laser, the jitter of the output signal and the external trigger signal is less than 10μ s. The laser can be used alone or as seed source of laser amplifier. At the same time, the laser amplifier of our company can be used to amplify the energy to tens of mJ. At the same time, the wavelength can be extended to 532nm, 355nm, 266nm, etc. The product has the advantages of good beam quality, high peak power, reliable performance, compact structure, simple operation and maintenance. Combined with excellent production technology, this series of products can meet the requirements of airborne, vehicle mounted, high and low temperature and other harsh environments.

Main features of this series of lasers:Sub-nanosecond, high peak power;High beam quality;High stability and compact structure;Strong environmental adaptability, working at -20 ~ 60 \degree ;1064nm, 532nm, 355nm wave-length optional;Typical application;Lidar;Laser micromachining;Nonlinear spectroscopy;Terahertz generation.

FEATURES

- Structural design of passive Q-switched microchip
- Narrow pulse width and high peak power
- · High stability and compact structure
- · Integrated photodetector

APPLICATIONS

- Laser Radar
- Point Cloud Imaging Radar
- Ranging
- Laser Remote Sensing
- Photoelectric Detection
- Laser Fine Processing





PARAMETERS

| | | CL532-60µJ-PQNL004 | CL532-120µJ-PQNL005 | CL532-200µJ-PQNL006 |
|-------------------------------|-----------------------|--------------------|---------------------|---------------------|
| Optical Parameter | Energy @532nm | > 60µJ | > 120µJ | > 200µJ |
| | Energy Stability | < 3% | < 3% | < 3% |
| | Repeat Frequency | 1~500Hz | 1~100Hz | 1~100Hz |
| | Pulse Width | < 1.5ns | < 1.5ns | < 1.5ns |
| Function Parameter | Control Interface | DB9,RS422 | DB9,RS422 | DB9,RS422 |
| | Cooling Method | Air Cooling | Air Cooling | Air Cooling |
| | powered By | 220VAC/50Hz | 220VAC/50Hz | 220VAC/50Hz |
| | Output Power | < 50W | < 80W | < 100W |
| Environmental Requirements | Operating Temperature | 15-40 ℃ | 15-40 ℃ | 15-40 ℃ |
| | Storage Temperature | -5-60 ℃ | -5-60℃ | - 5-60 ℃ |
| | Humidity | 0-80% | 0-80% | 0-80% |
| Weight & Size | Laser Weight | < 10kg | < 12kg | < 15kg |
| | Laser Size | 441*117*96mm | 480*120*96mm | 520*120*96mm |

SRUCTURE





